

## Standard Rectifier Module

$$\begin{aligned} V_{RRM} &= 1600 \text{ V} \\ I_{FAV} &= 608 \text{ A} \\ V_F &= 1.01 \text{ V} \end{aligned}$$

### Single Diode

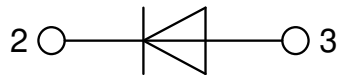
#### Part number

**MDO600-16N1**



Backside: isolated

 E72873



#### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

#### Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

#### Package: Y1

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Base plate: Copper internally DCB isolated
- Advanced power cycling

#### Terms and Conditions of Usage

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office.

Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office.

Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

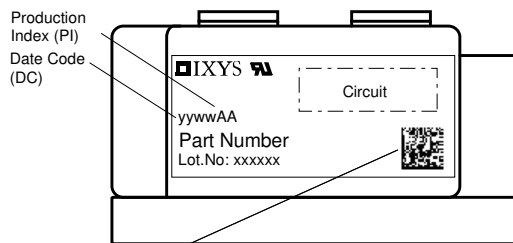
- to perform joint risk and quality assessments;

- the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

Rectifier				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
$V_{RSM}$	max. non-repetitive reverse blocking voltage			$T_{VJ} = 25^{\circ}C$		1700	V
$V_{RRM}$	max. repetitive reverse blocking voltage			$T_{VJ} = 25^{\circ}C$		1600	V
$I_R$	reverse current	$V_R = 1600$ V		$T_{VJ} = 25^{\circ}C$		1	mA
		$V_R = 1600$ V		$T_{VJ} = 140^{\circ}C$		30	mA
$V_F$	forward voltage drop	$I_F = 600$ A		$T_{VJ} = 25^{\circ}C$		1.12	V
		$I_F = 1200$ A				1.30	V
		$I_F = 600$ A		$T_{VJ} = 125^{\circ}C$		1.01	V
		$I_F = 1200$ A				1.23	V
$I_{FAV}$	average forward current	$T_C = 85^{\circ}C$		$T_{VJ} = 140^{\circ}C$		608	A
		180° sine	d = 0.5				
$V_{FO}$	threshold voltage			$T_{VJ} = 140^{\circ}C$		0.76	V
$r_F$	slope resistance					0.32	mΩ
						} for power loss calculation only	
$R_{thJC}$	thermal resistance junction to case					0.072	K/W
$R_{thCH}$	thermal resistance case to heatsink				0.024		K/W
$P_{tot}$	total power dissipation			$T_C = 25^{\circ}C$		1600	W
$I_{FSM}$	max. forward surge current	t = 10 ms; (50 Hz), sine		$T_{VJ} = 45^{\circ}C$		15.0	kA
		t = 8,3 ms; (60 Hz), sine		$V_R = 0$ V		16.2	kA
		t = 10 ms; (50 Hz), sine		$T_{VJ} = 140^{\circ}C$		12.8	kA
		t = 8,3 ms; (60 Hz), sine		$V_R = 0$ V		13.8	kA
$I^2t$	value for fusing	t = 10 ms; (50 Hz), sine		$T_{VJ} = 45^{\circ}C$		1.13	MA <sup>2</sup> s
		t = 8,3 ms; (60 Hz), sine		$V_R = 0$ V		1.09	MA <sup>2</sup> s
		t = 10 ms; (50 Hz), sine		$T_{VJ} = 140^{\circ}C$		812.8	kA <sup>2</sup> s
		t = 8,3 ms; (60 Hz), sine		$V_R = 0$ V		788.8	kA <sup>2</sup> s
$C_J$	junction capacitance	$V_R = 400$ V; f = 1 MHz		$T_{VJ} = 25^{\circ}C$		762	pF

Package Y1				Ratings		
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal			600	A
$T_{VJ}$	virtual junction temperature		-40		140	°C
$T_{op}$	operation temperature		-40		125	°C
$T_{stg}$	storage temperature		-40		125	°C
<b>Weight</b>					650	g
$M_D$	mounting torque		4.5		7	Nm
$M_T$	terminal torque		11		13	Nm
$d_{Spp/App}$	creepage distance on surface   striking distance through air	terminal to terminal	16.0			mm
$d_{Spb/Apb}$		terminal to backside	25.0			mm
$V_{ISOL}$	isolation voltage	t = 1 second	3600			V
		t = 1 minute	3000			V



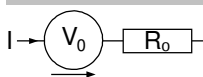
Data Matrix: part no. (1-19), DC + PI (20-25), lot.no.# (26-31), blank (32), serial no.# (33-36)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MDO600-16N1	MDO600-16N1	Box	2	509707

### Equivalent Circuits for Simulation

\* on die level

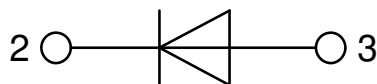
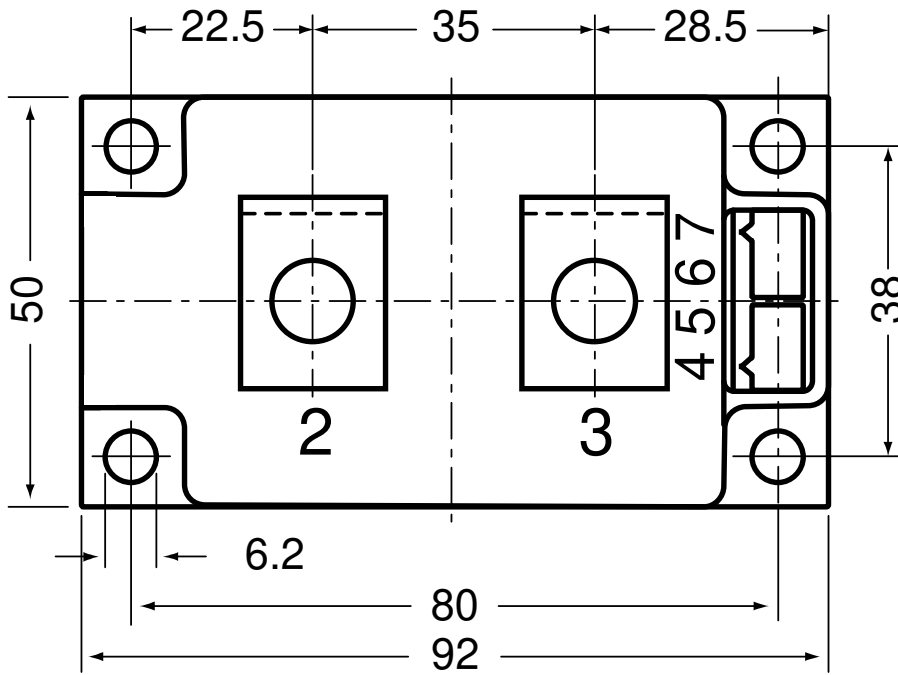
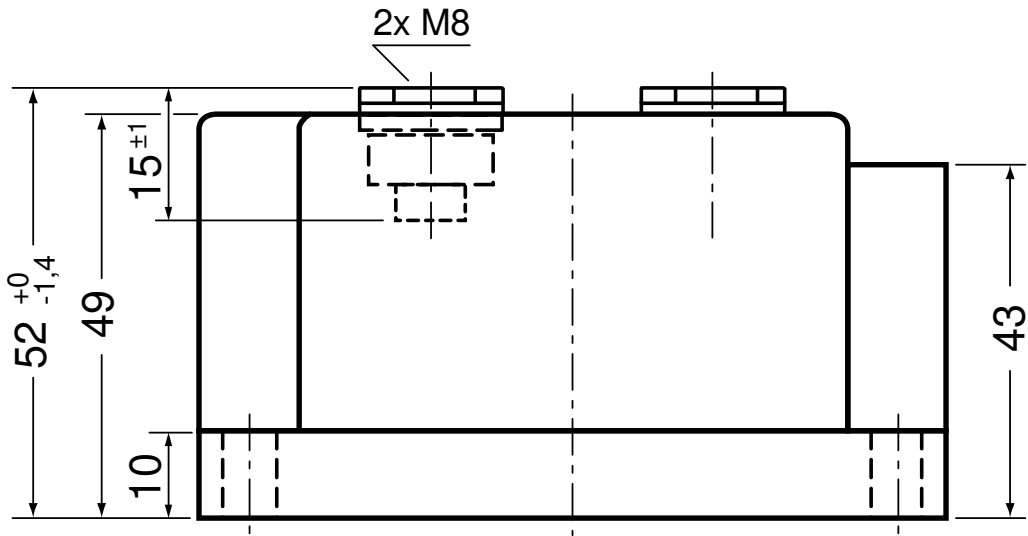
$T_{VJ} = 140\text{ °C}$



Rectifier

$V_{0\ max}$	threshold voltage	0.76	V
$R_{0\ max}$	slope resistance *	0.13	mΩ

Outlines Y1



## Rectifier

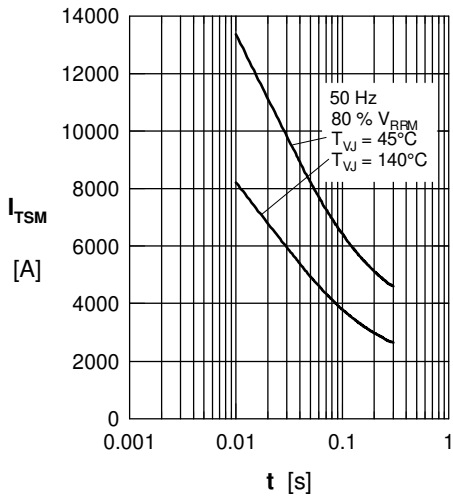


Fig. 1 Surge overload current  
 $I_{FSM}$ : Crest value, t: duration

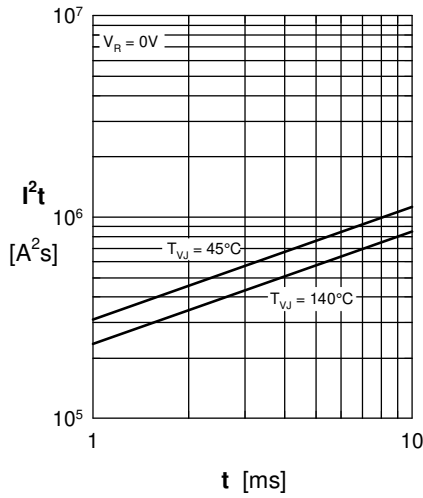


Fig. 2  $I^2t$  versus time (1-10 ms)

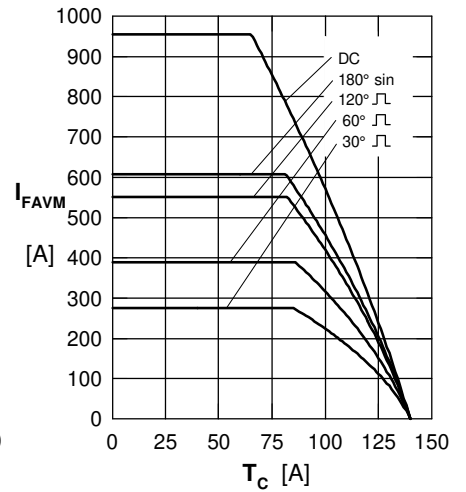


Fig. 3 Max. forward current at case temperature

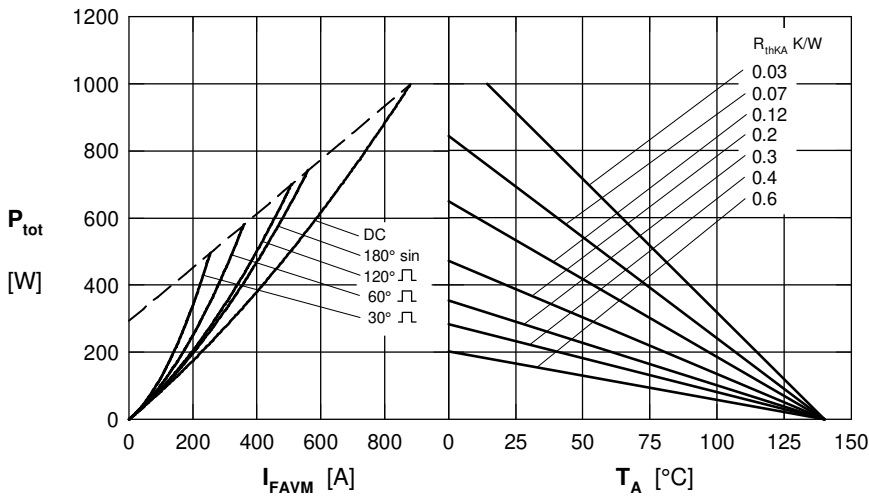


Fig. 4 Power dissipation vs. forward current and ambient temperature

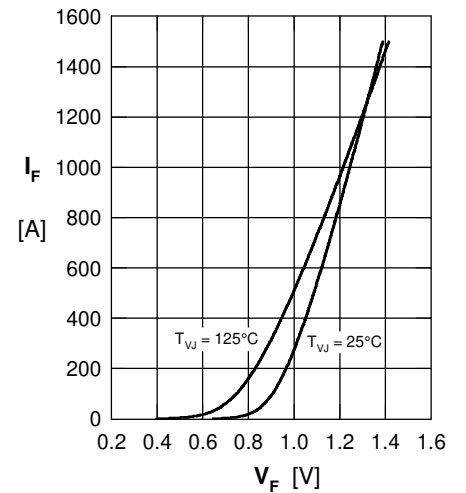


Fig. 5 Forward current  $I_F$  vs.  $V_F$

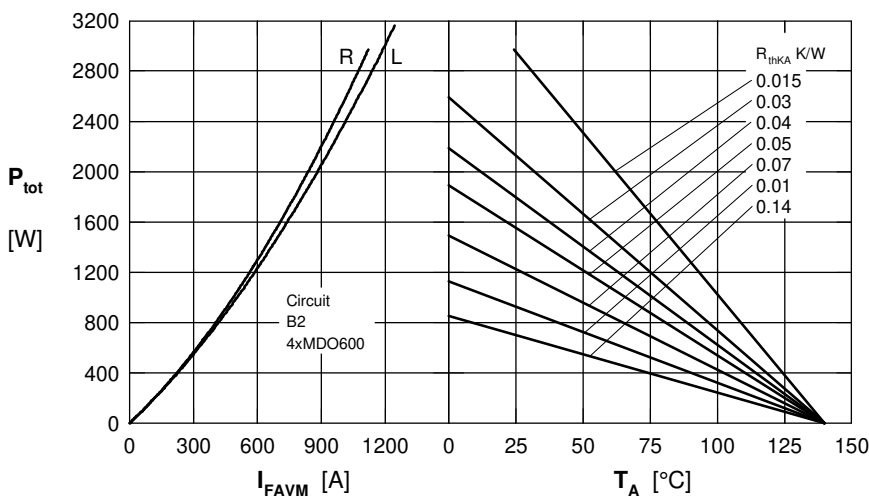


Fig. 6 Single phase rectifier bridge: Power dissipation vs. direct output current and ambient temperature R = resistive load, L = inductive load

**Rectifier**

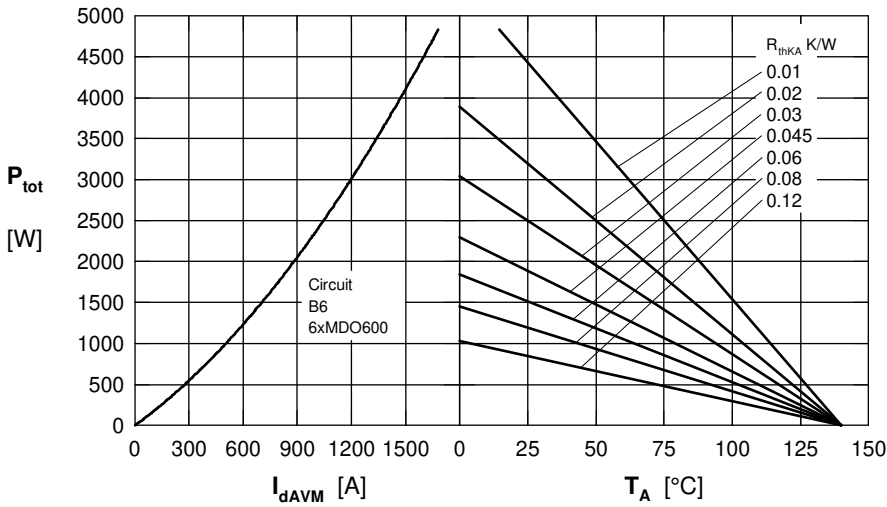


Fig. 7 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

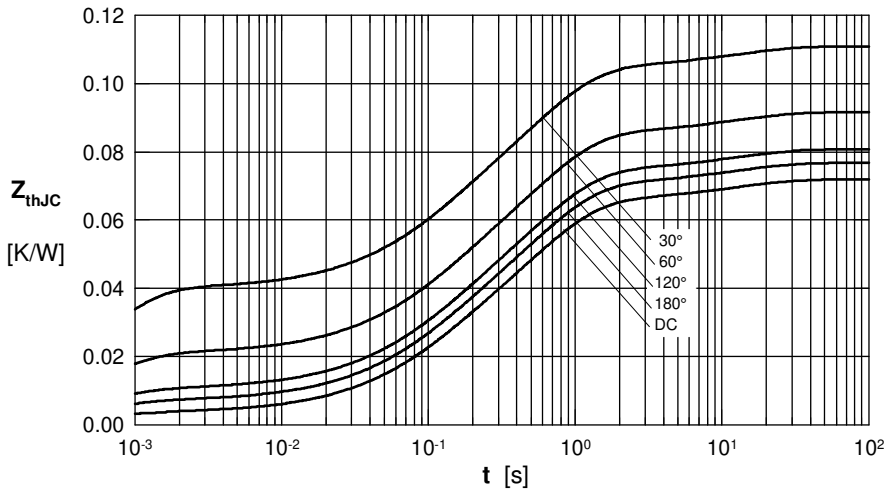


Fig. 8 Transient thermal impedance junction to case

$R_{thJC}$  for various conduction angles d:

d	$R_{thJC}$ (K/W)
DC	0.072
180°	0.0768
120°	0.081
60°	0.092
30°	0.111

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.0035	0.0054
2	0.0186	0.098
3	0.0432	0.54
4	0.0067	12

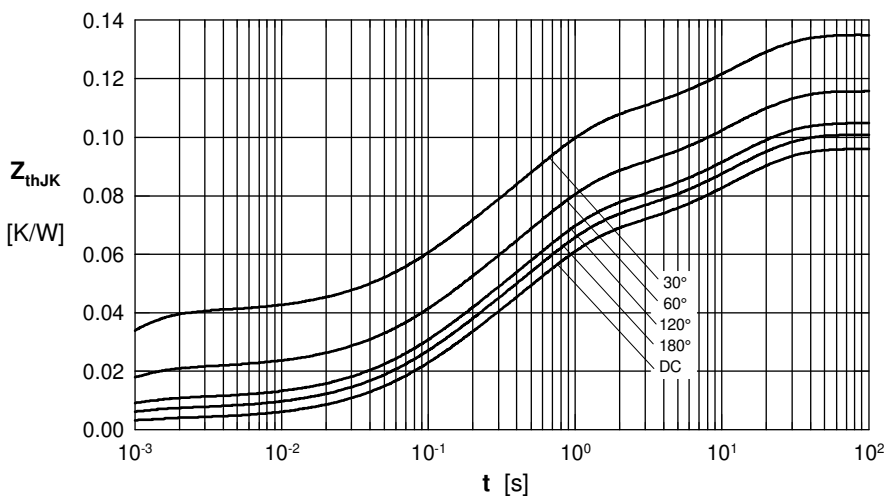


Fig. 9 Transient thermal impedance junction to heatsink

$R_{thJK}$  for various conduction angles d:

d	$R_{thJK}$ (K/W)
DC	0.096
180°C	0.1
120°C	0.105
60°C	0.116
30°C	0.135

Constants for  $Z_{thJK}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.0035	0.0054
2	0.0186	0.098
3	0.0432	0.54
4	0.067	12
5	0.024	12